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## **FDS6675** Single P-Channel, Logic Level, PowerTrench<sup>™</sup> MOSFET

#### **General Description**

This P-Channel Logic Level MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain low gate charge for superior switching performance.

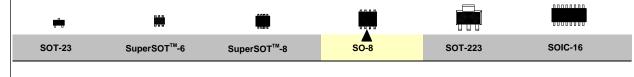
These devices are well suited for notebook computer applications: load switching and power management, battery charging circuits, and DC/DC conversion.

#### Features

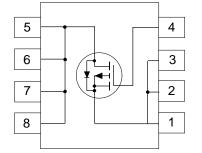
- $\label{eq:linear_state} \begin{array}{c} \bullet & -11 \text{ A}, \ -30 \ \text{V}. \ \text{R}_{\text{DS(ON)}} = 0.014 \ \Omega \ @ \ \text{V}_{\text{GS}} = -10 \ \text{V}, \\ \text{R}_{\text{DS(ON)}} = 0.020 \ \Omega \ @ \ \text{V}_{\text{GS}} = -4.5 \ \text{V}. \end{array}$
- Low gate charge (30nC typical).
- High performance trench technology for extremely low  $\mathsf{R}_{\mathsf{DS}(\mathsf{ON})}.$

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• High power and current handling capability.







#### **Absolute Maximum Ratings** $T_{A} = 25^{\circ}C$ unless otherwise noted

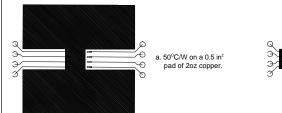
Symbol	Parameter	FDS6675	Units
V <sub>DSS</sub>	Drain-Source Voltage	-30	V
V <sub>GSS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current - Continuous (Note 1a)	-11	A
	- Pulsed	-50	
P <sub>D</sub>	Power Dissipation for Single Operation (Note 1a)	2.5	W
	(Note 1b)	1.2	
	(Note 1c)	1	
Г <sub>Ј</sub> ,Т <sub>STG</sub>	Operating and Storage Temperature Range	-55 to 150	°C
THERMA	L CHARACTERISTICS		-
۲ <sub>өла</sub>	Thermal Resistance, Junction-to-Ambient (Note 1a)	50	°C/W
R <sub>euc</sub>	Thermal Resistance, Junction-to-Case (Note 1)	25	°C/W

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Symbol	Parameter	Conditions		Min	Тур	Max	Units
OFF CHAR	ACTERISTICS						
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_{D} = -250 \mu A$		-30			V
$\Delta BV_{DSS} / \Delta T_{J}$	Breakdown Voltage Temp. Coefficient	$I_{\rm D}$ = -250 µA, Referenced to 25 °C			-22		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{\rm DS} = -24 \text{ V}, \ V_{\rm GS} = 0 \text{ V}$				-1	μA
			T <sub>J</sub> = 55°C			-10	μA
	Gate - Body Leakage, Forward	$V_{GS} = 20 \text{ V}, V_{DS} = 0 \text{ V}$				100	nA
GSSR	Gate - Body Leakage, Reverse	$V_{GS} = -20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$				-100	nA
	CTERISTICS (Note 2)						
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$		-1	-1.7	-3	V
$\Delta V_{GS(th)} / \Delta T_J$	Gate Threshold Voltage Temp. Coefficient	$I_{D}$ = 250 µA, Referenced to	$I_p = 250 \ \mu$ A, Referenced to $25 \ ^{\circ}$ C		4.3		mV/°C
R <sub>DS(ON)</sub>	Static Drain-Source On-Resistance	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -11 \text{ A}$			0.011	0.014	Ω
			T <sub>J</sub> =125°C		0.016	0.023	
		$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -9 \text{ A}$	•		0.015	0.02	
I <sub>D(ON)</sub>	On-State Drain Current	$V_{GS} = -10 \text{ V}, V_{DS} = -5 \text{ V}$		-50			А
9 <sub>FS</sub>	Forward Transconductance	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -11 \text{ A}$			32		S
DYNAMIC (	CHARACTERISTICS						
C <sub>iss</sub>	Input Capacitance	$V_{DS} = -15 V, V_{GS} = 0 V,$ f = 1.0 MHz			3000		pF
C <sub>oss</sub>	Output Capacitance				870		pF
C <sub>rss</sub>	Reverse Transfer Capacitance				360		pF
SWITCHING	CHARACTERISTICS (Note 2)						
t <sub>D(on)</sub>	Turn - On Delay Time	$V_{DS} = -15 V, I_{D} = -1 A$			12	22	ns
t,	Turn - On Rise Time	$V_{\text{GEN}}$ = -10 V, $R_{\text{GEN}}$ = 6 $\Omega$			16	27	ns
t <sub>D(off)</sub>	Turn - Off Delay Time				50	80	ns
t,	Turn - Off Fall Time				100	140	ns
Q <sub>g</sub>	Total Gate Charge	$V_{DS} = -15 V, I_{D} = -11 A,$ $V_{GS} = -5 V$			30	42	nC
Q <sub>gs</sub>	Gate-Source Charge				9		nC
Q <sub>gd</sub>	Gate-Drain Charge				11		nC
DRAIN-SOU	RCE DIODE CHARACTERISTICS AND MAX	(IMUM RATINGS					
I <sub>s</sub>	Maximum Continuous Drain-Source Diode Forward Current					-2.1	А
V <sub>SD</sub>	Drain-Source Diode Forward Voltage $V_{GS} = 0 \text{ V}, I_{S} = -2.1 \text{ A}$ (Note 2)			-0.72	-1.2	V	

Notes:

1. R<sub>BW</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>BW</sub> is guaranteed by design while R<sub>BW</sub> is determined by the user's board design.



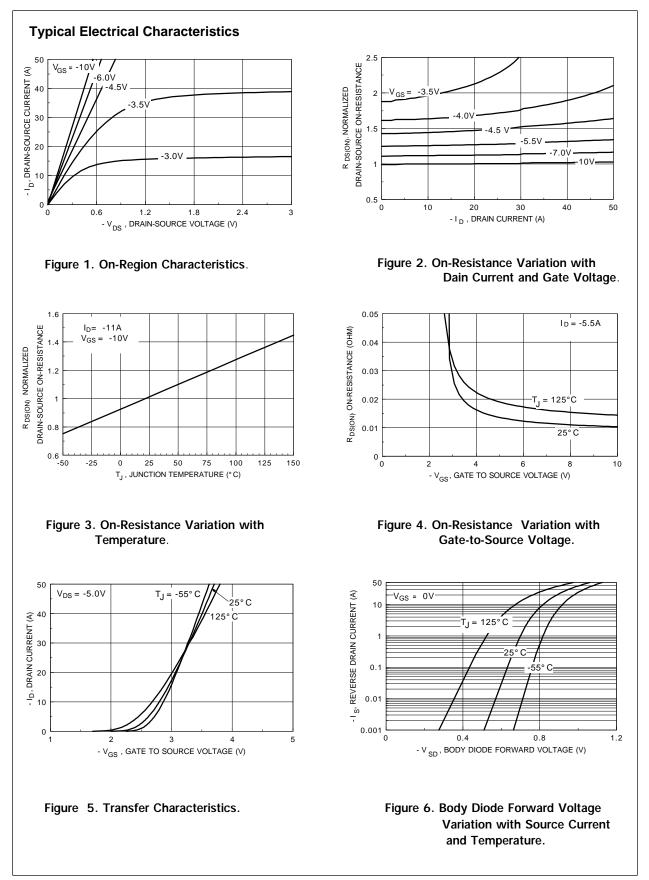




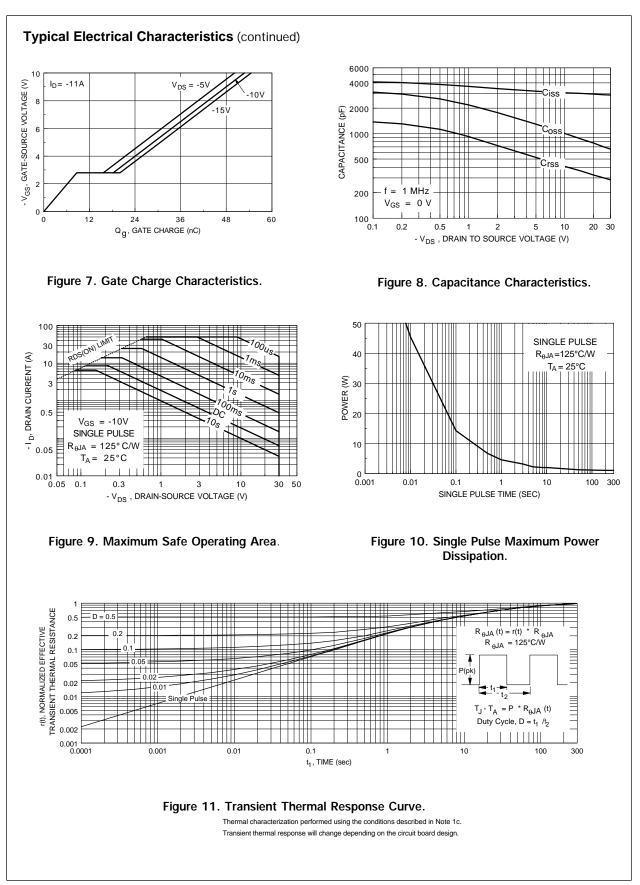
b. 105°C/W on a 0.02 in<sup>2</sup> pad of 2oz copper.

Scale 1 : 1 on letter size paper

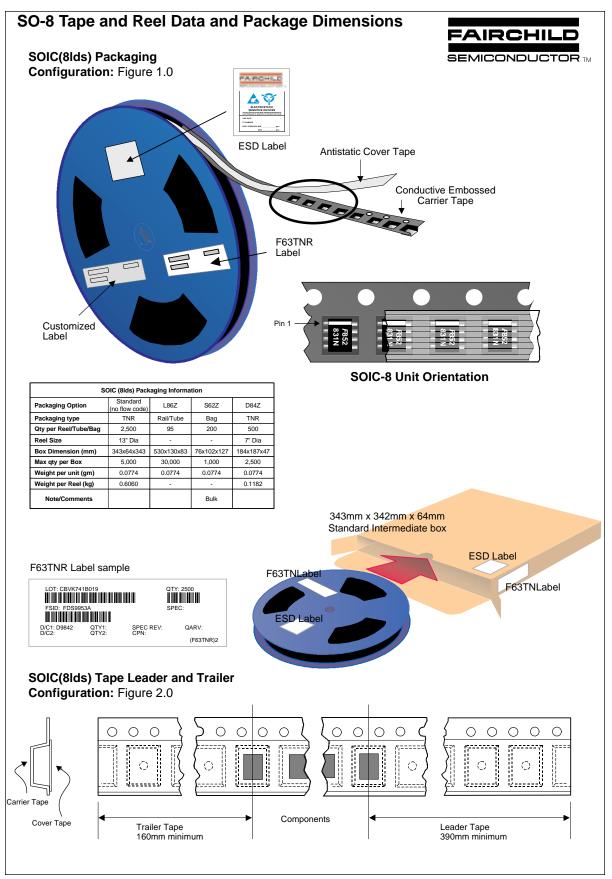
2. Pulse Test: Pulse Width  $\underline{<}$  300µs, Duty Cycle  $\underline{<}$  2.0%.



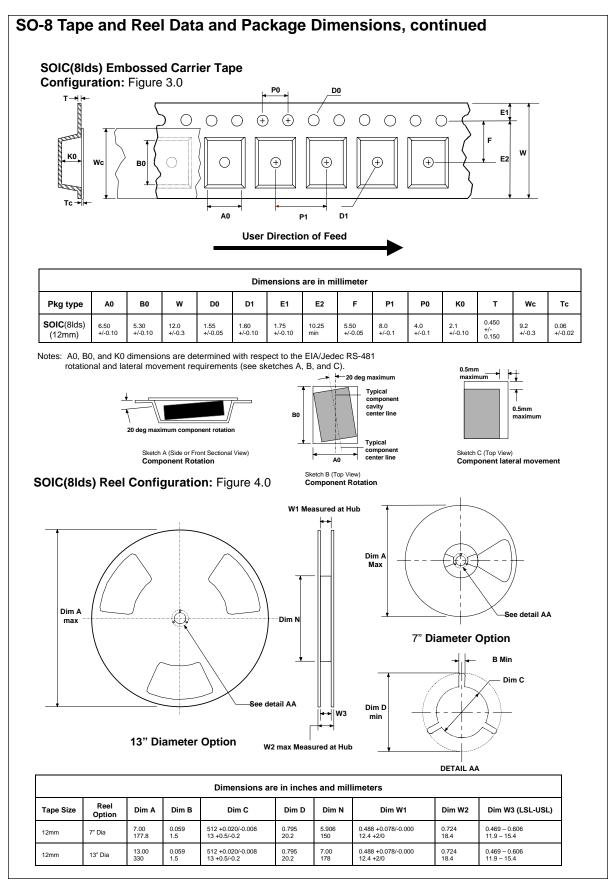
FDS6675 Rev.C



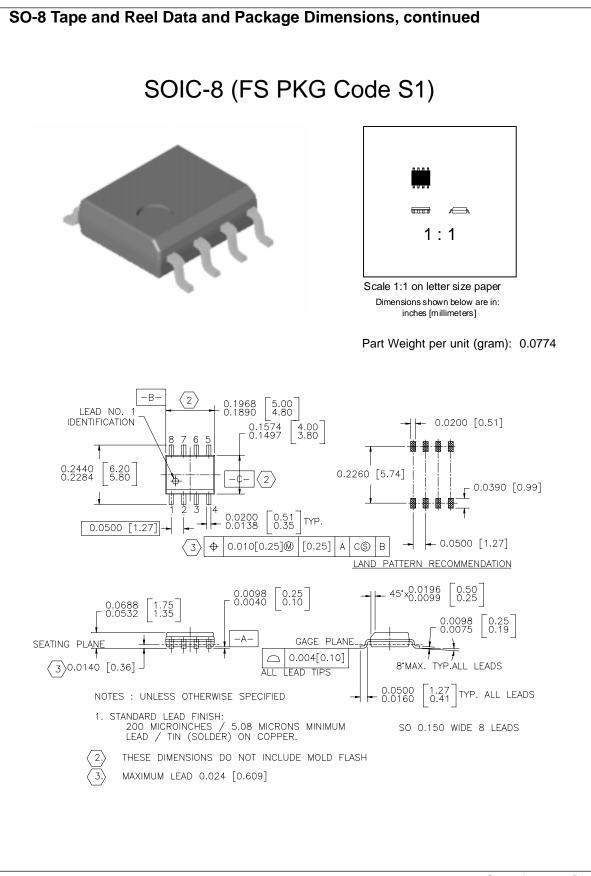
FDS6675 Rev.C



November 1998, Rev. A



November 1998, Rev. A



September 1998, Rev. A

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